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### 공학석사학위논문

# Effect of Surface Characteristics of Reduced Graphene Oxide on the Performance of Pseudocapacitor

환원된 그래핀 옥사이드의 표면특성이 유사커패시터 성능에 미치는 영향

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#### **Abstract**

## Effect of Surface Characteristics of Reduced Graphene Oxide on the Performance of Pseudocapacitor

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It is well known that reduced graphene oxide (rGO) has been intensely researched for applications in supercapacitors and rGO/metal oxide composite have also been spotlighted for its pseudocapacitive effects. Though metal oxides have high specific capacitance and electrochemical stability, they also show poor rate capability and low accessible surface areas. In order to overcome these problems, many fabrication methods of the composite has been suggested, such as, microwave assisted reflux methods by Rao et al., and electrochemical deposition method by Cao et al., which showed high specific capacitance values. However, other than just fabricating a composite and showing that it has a high value as listed above, no research has been done on verifying which kind of rGO plays the ideal role as a substrate for metal oxide composites in terms of rGO's surface characteristics, chemical properties, and

preparation methods.

Therefore, it came to our interest, that in order to fabricate rGO/metal oxide

supercapacitor with high electrochemical performance, not only do we need to research

on the composite fabrication methods, but also need to provide a guideline of how to

prepare rGO substrate of different size, and functional groups. In this research, we

analyzed the electrochemical characteristics of the different rGO/Co<sub>3</sub>O<sub>4</sub> composites

prepared by controlling rGO's surface characteristics and its relationship between the

performance of the pseudocapacitor, providing a guideline for the ideal fabrication of

rGO/metal oxide composite for psuedocapacitor. This way, further researches using

rGO as electrode material for pseudocapacitors can, from now on, take our research

into account for improved electrochemical performances.

keywords: reduced graphene oxide, oxygen functional groups, metal oxide,

electrochemical performance, pseudocapacitor.

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### 1. Introduction

### 1.1 Introduction to rGO/Co<sub>3</sub>O<sub>4</sub> pseudocapacitor

### 1.1.1 rGO as electrode material for supercapacitor and its EDLC behavior

Reduced graphene oxide (rGO), a 3-D stacked layers of oxygenated graphene, has been researched in many areas such as catalysts [1], hydrogen storage [2], organic solar cells [3], supercapacitors [4] and etc. As seen in Figure 1 [5], It has been statistically analyzed that graphene-based products will increase dramatically in less than 10 years, especially in the area of capacitors. Therefore, many researches have been done on using rGO as a substrate material for supercapacitor and are still in progress.

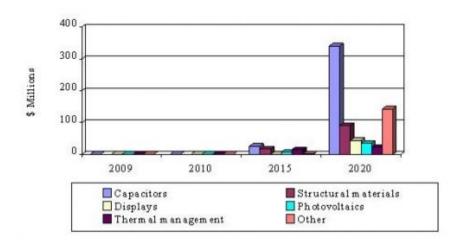


Figure 1: Global Market for Graphene-based Products, 2009-2020 (\$ Millions)

rGO has many advantages such as having wide potential window, large surface area, good flexibility, and good chemical & thermal stability [6]. Because of its large surface area, it is suitable to be used as a porous substrate for supercapacitor as porosity and surface area is an important factor when discussing the electrochemical performance of supercapacitors [7]. As shown in Figure 2a [8], rGO usually shows an electric double layer capacitance behavior (EDLC) because it interacts with electrolyte ions through electrostatic reactions where the ions solely adsorb onto the surface of the rGO substrate without chemical reaction [9]. Thus, providing a cyclic voltammetry graph of a symmetrical and rectangular shape as seen in Figure 2b [8].

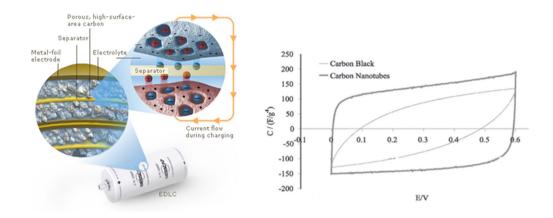


Figure 2: a) Behavior of EDLC b) cyclic voltammetry of EDLC

However, because rGO has poor electrical conductivity, rGO alone as a supercapacitor material lacks the electrochemical performance of the device [10]. Therefore, many researches have been done in incorporating peudocapacitive materials such as metal oxides in order to create synergistic effects and improve the electrochemical performance [11].

### 1.1.2 Metal oxide (MO) as electrode material for pseudocapacitor and its pseudocapacitive behavior

By introducing the loading of metal oxides (MO) onto the surface of rGO,

synergistic effects of porosity of rGO and well defined redox mechanism of MO have been known to improve the electrochemical performance of the pseudocapacitor [4]. Since metal oxides have very high theoretical specific capacitance with well-defined redox mechanism, it contributes greatly to the pseudocapacitive behavior of the pseudocapacitor [9]. As seen in Figure 3a [12], when compared to rGO, MO interact with electrolyte ions through electrochemical reaction where redox reactions happen between MO and the ions. Meaning, there must be a change in the oxidation state of the metal oxide as it reacts with the charged electrolyte ions. Thus, giving pseudocapacitive peaks in cyclic voltammetry as seen in Figure 3b [12].

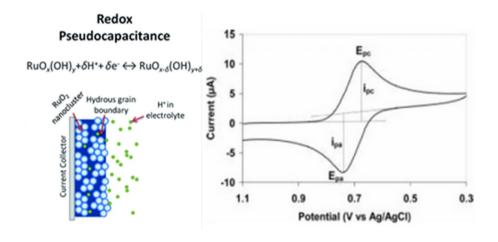


Figure 3: a) Behavior of pseudocapacitor b) cyclic voltammetry of pseudocapacitor

Many metal oxides have been researched on as candidates for electrode materials. Among them, ruthenium oxide (RuO<sub>2</sub>) and iridium oxide (IrO<sub>2</sub>) show very high electrochemical performance, however these noble metal oxides are very

expensive, thus giving us restraints to using them commercially [4]. Therefore, alternate cheap metal oxides have been researched on such as manganese oxide (MnO<sub>2</sub>) [13], ferric oxide (Fe<sub>2</sub>O<sub>3</sub>) [14], nickel oxide (NiO) [15], and cobalt oxide (Co<sub>3</sub>O<sub>4</sub>) [16].

We have decided to use Co<sub>3</sub>O<sub>4</sub> as our metal oxide material because of its advantages such as having low cost, high redox reactivity, high theoretical specific capacitance (~3560 F/g), and high reversibility [4]. By incorporating Co<sub>3</sub>O<sub>4</sub> into rGO substrate, we were able to fabricate rGO/MO pseudocapacitor

#### 1.1.3 Important factors for performance of pseudocapacitor

It is important to consider different parameters that affect the electrochemical performance of pseudocapacitors. In order to achieve high electrochemical performance, the pseudocapacitor must show high specific capacitance. Specific capacitance can be calculated using the following equation [17]:

$$C_{sp} = \frac{\int I(V)dV}{mv\Delta V} = \left(\frac{\varepsilon_r \varepsilon_o}{d}\right) \tag{1}$$

Where  $C_{sp}$ , I, m, v, and  $\Delta V$  are specific capacitance, current at charge-discharge, mass of 2 electrodes, scan rate, and potential window respectively. And  $\varepsilon_r$ ,  $\varepsilon_o$ , d, A are relative permittivity, permittivity of vacuum, effective thickness of the supercapacitor, and specific surface are of the electrode respectively. The parameters  $\int I$ , v, and  $\Delta V$ 

may be obtained from cyclic voltammetry graphs such as the one shown in Figure 3b.

In order to increase the specific capacitance values, the parameters  $\varepsilon_r$ , d, and A are important to consider. These parameters solely consider the nature of the supercapacitor itself. In order to increase  $\varepsilon_r$ , the resistance between the electrode material and the electrolyte should be small. In order to control d, the porosity of the electrode material should be controlled. In order to increase the specific surface area, the electrode material must be very porous [4]. Thus, combining all these factors, we generally want high accumulation of electrolyte ions at the surface of the electrode in order to increase the electrical current value, I.

### 1.1.4 State-of-the-art (SOA) of rGO/Co<sub>3</sub>O<sub>4</sub> pseudocapacitors

Currently, many researches have been done on using rGO and  $Co_3O_4$  electrode materials for pseudocapacitors. Though all of these researches indicate that they have similarly used rGO as the porous substrate material and  $Co_3O_4$  as the metal oxide material in the pseudocapacitor, they each show very different morphologies of the  $Co_3O_4$  nanoparticles and very different specific capacitance values as shown in Table 1:

Table 1: SOA of rGO/Co<sub>3</sub>O<sub>4</sub> pseudocapacitors

Composite	Method	Specific capacitance (F/g)	Goal stated/Abstract	Reference
rGO/Co <sub>3</sub> O <sub>4</sub> composite	Hydrothermal Synthesis (varying ratio of rGO:Co <sub>3</sub> O <sub>4</sub> )	263	000 - 0000pt   0000- 0000pt   0000- 0000pt   0000- 0000pt   0000- 0000- 0000pt   0000- 0000- 0000   0000- 0000- 0000- 0000   0000- 0000	J Mater Sci 48 (2013) 8463–8470
rGO in Co₃O₄ matrix	Chemical Synthesis (varying ratio of rGO:Co <sub>3</sub> O <sub>4</sub> )	291	V 4 1	Materials Chemistry and Physics 130 (2011) 672 – 679
Co <sub>3</sub> O <sub>4</sub> hollow spheres/rGO composite	Solvothermal synthesis	360	20 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	Current Applied Physics 13 (2013) 1796 – 1800
Co <sub>3</sub> O <sub>4</sub> /graphene composite	Chemical Synthesis (varying heat treatment)	396	The second secon	Carbon Letters Vol. 13, No. 2, (2012) 130-132
Co <sub>3</sub> O <sub>4</sub> /rGO Nanosheets	Hydrothermal Synthesis (varying ratio of rGO:Co <sub>3</sub> O <sub>4</sub> )	400	2 75	Electrochimica Acta 112 (2013) 120 – 126

These researches use similar methods; either hydrothermal or chemical synthesis. However they show very different electrochemical performance. An effort they have tried to improve the electrochemical performance is by varying the ratio of  $rGO:Co_3O_4$ , which is a very common way to improve the performance. An example can be seen in Figure 4a, where we can see that the specific capacitance value increases with the ratio of  $rGO:Co_3O_4[17]$ .

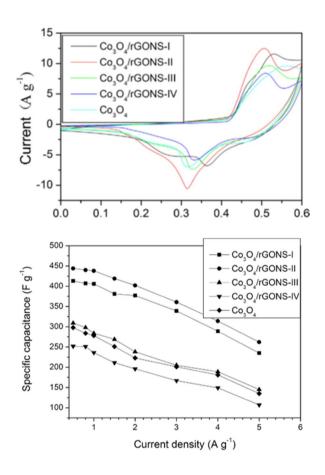


Figure 4: a) Cyclic voltammetry of rGO/Co<sub>3</sub>O<sub>4</sub> pseudocapacitor with varying ratio b) Specific capacitances of rGO/Co<sub>3</sub>O<sub>4</sub> pseudocapacitor

### 1.1.5 Limitation of the state-of-the-art of rGO/Co<sub>3</sub>O<sub>4</sub> pseudocapacitors

As mentioned in the previous section, the researches of the SOA all similarly use rGO and Co<sub>3</sub>O<sub>4</sub> as the electrode material for pseudocapacitor with similar methods. However, they all show very different morphologies and electrochemical performance. These researches only show how to synthesize rGO/MO composite through simple methods just to prove that the pseudocapacitor has a very high specific capacitance and no other research is done on the surface characteristics of the rGO substrate itself. There must be an influence from the graphite precursor itself which gives different graphene oxides with different surface properties and we believe that these properties such as the oxygen functional groups affect the growth of metal oxides on the surface of the rGO substrate.

Therefore, no research was done on verifying which kind of rGO plays the ideal role as a substrate material for the growth of metal oxides in terms of rGO's surface characteristics, chemical properties, and its preparation methods from the graphite precursors. We, therefore, suggest that there must be a difference in electrochemical performance depending on the morphologies of how the metal oxides grew on the surface of the rGO substrate, which we believe is affected by the amount of oxygen functional groups attached.

### 1.2 The growth of metal oxide on the oxygen functionalized rGO substrate

#### 1.2.1 Interaction of rGO and metal oxides

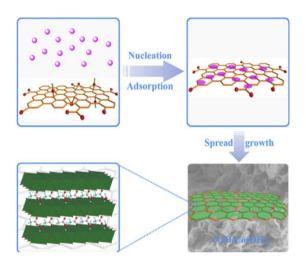


Figure 5: Reaction scheme of reaction between MO and GO

Metal oxides have interfacial interactions with GO by two different types of mechanisms. The first mechanism is the reactive chemisorption on functional groups that bridge the metal centers at the oxygen defect sites. The second mechanism is the Van der Waals interactions between the pristine region of graphene and metal oxides. The reaction scheme can be briefly seen in Figure 5 [4]:

Where the metal oxides first adsorb onto the surface of rGO, then nucleates throughout

the surface, and finally undergoes spread growth to give a rGO/MO composite. Therefore the content of oxygen functional groups attached on the surface of rGO is an important factor to consider.

### 1.2.2 Growth of metal oxides and its interaction with the functional groups of the rGO

By looking at the SOA of rGO/Co<sub>3</sub>O<sub>4</sub> pseudocapacitors, it has come to our attention that there must be an influence of the growth of metal oxides from the surface characteristics of rGO. From looking at the following SOA and Figure 6 [18]:

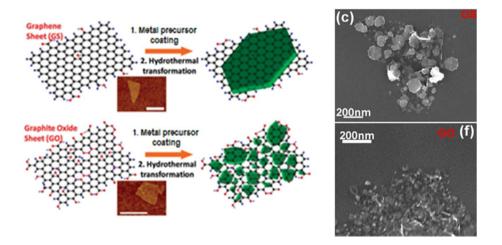


Figure 6: SOA suggesting the difference in growth of MO depending on functional groups attached on GO

We can see that the growth of metal oxides depend on the amount of functional groups attached on the surface of rGO. The graphene sheet with small amount of functional groups show that the metal oxides agglomerate and grow into each other into a big chunk of metal oxide while graphene oxide sheet with large amount of functional groups show that the metal oxides are pinned in between the functional groups and prevent the metal oxides from growing into each other and maintain its crystalline shape as small clusters. From this, we can assume that there must be a difference in the electrochemical performance depending on the available redox reaction sites on the surface of rGO.

### 1.2.3 Controlling the functional groups of rGO through oxidation

Based on J. Kang's research, the amount of functionalized groups attached on the surface of rGO can be controlled by controlling the oxidation time in the modified Hummer's method. As shown in Figure 7 [19]:

Step 1) 
$$H_2SO_4 + KMnO_4 + graphite -> Mn_2O_7 + graphite$$

$$H_2O$$
Step 2)  $MnO_4$  + graphene oxide
$$H_2O_2$$
Step 3)  $Mn^+$  + graphene oxide

Figure 7: Steps of oxidation of GO

While previous researches focused on step 1, Kang suggested that we must also investigate step 2 and prove that by controlling this step, we may be able to control the amount of functional groups attached on the surface of rGO. Thus, as-proven, by increasing the oxidation time of step 2, we were able to increase the oxygen functional groups and therefore expect the following visualized scheme of the varying GOs in Figure 8:

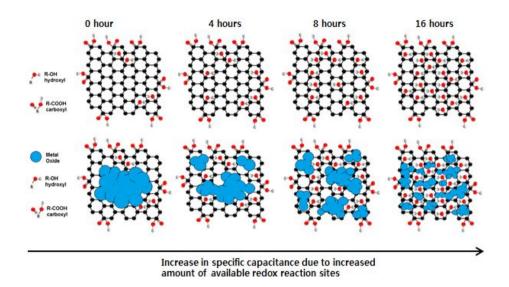


Figure 8: Expectation of the growth of MO on the varied functionalized GO surfaces

### 1.2.4 Graphite precursors

We will also need to consider the two most commonly used graphite precursors known as small/crumpled graphite (400 mesh) of size  $\sim$ 2 $\mu$ m and large/planar graphite (30mesh) of size  $\sim$ 500 $\mu$ m, which the size difference can be seen in the optical microscopy image in Figure 9a and 9b. After we have distinguished which precursor is a better substrate for growing metal oxides, we will use that graphite precursor to vary the oxidation time and functional groups and continue with the remaining research.

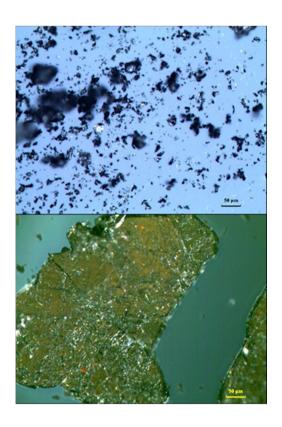


Figure 9: Optical microscopy images of a) small/crumpled GO and b) large/planar GO

### 1.3 The goal of this research

Again, re-iterating the limitation of the previous researches on the  $rGO/Co_3O_4$  pseudocapacitors, the researches typically fabricate a composite and show that it has a high value. No research was done on verifying which kind of rGO plays the ideal role as a substrate for the growth of metal oxides in terms of rGO's surface characteristics, chemical properties, and its preparation methods.

Therefore, we decided to provide a guideline of how to prepare rGO substrate - 23 -

of different chemical properties and functional groups and its effect of the growth of metal oxides and analyze its relationship between the performance of the pseudocapacitor.

### 2. Experimental

### 2.1 Preparation of varied surface properties of rGO

#### 2.1.1 Materials

Small/crumpled graphite precursor (GO (C)), large/planar graphite precursor (GO (P)) purchased from Sigma-Aldrich Korea. KMnO<sub>4</sub> ( $\geq$ 99.0%), (CH<sub>3</sub>COO)<sub>2</sub>Co·6H<sub>2</sub>O were purchased from Sigma-Aldrich Korea, H<sub>2</sub>SO<sub>4</sub> ( $\geq$ 98.0%), H<sub>2</sub>O<sub>2</sub>, ammonia hydroxide were purchased from Daejung Chemical.

### 2.1.2 Oxidation of GO(C) and GO(P)

Modified Hummer's method was used for the oxidation of GO. 2.4g of graphite flake was pre-oxidized with 2.0g of potassium persulfate and 2.0g of pentoxide solution in 10ml of concentrated sulfuric acid at 80 °C for 3days. The expanded graphite was then poured into D.I. water and vacuum filtered and washed again with D.I. water and vacuum dried at room temperature overnight. Step 1: Expanded graphite was then oxidized with 12g KMnO<sub>4</sub> in 92 ml of concentrated sulfuric acid at 35 °C for 2.5h. Then the mixture was cooled to 0 °C and 1.0L of D.I. water was poured into the mixture within 30 minutes. Step 2: then 10ml H<sub>2</sub>O<sub>2</sub> solution

was put to terminate the oxidation. The obtained GO precipitate was then centrifuged at 10,000 rpm for 15 min and mixed with 1M HCl solution and centrifuged for 3 more times in order to remove the oxidation impurities. Finally, GO was neutralized with D.I. water by centrifugation at 13,000 rpm for 40 min until the PH value became over 5.0 [20,21]

#### 2.1.3 Oxidation of GO(P) at 0h, 4h, 8h, 16h oxidation time

For this part, we incorporated J.H. Kang's oxidation method by increasing the oxidation time of step 2 and left the other parts the same as above. For 0h sample, 10ml  $H_2O_2$  solution was poured after 30 min as indicated above. For 4h, 10ml  $H_2O_2$  solution was poured after 4 hours. For 8h, 10ml  $H_2O_2$  solution was poured after 8 hours. For 16h, 10ml  $H_2O_2$  solution was poured after 16 hours.

A total of 5 different kinds of GO samples were prepared: crumpled GO (oxidation time 0h) will be noted as GO (C), planar GO (oxidation time 0h, 4h, 8h, 16h) will be noted as GO (P-0), GO (P-4), GO (P-8), GO (P-16).

### 2.2 Preparation of rGO/Co<sub>3</sub>O<sub>4</sub> pseudocapacitor

#### 2.2.1 Preparation of rGO/Co<sub>3</sub>O<sub>4</sub> composites

The composite was prepared by the method suggested by others [18,22]. 70mg of GO in 70ml D.I. water is dispersed in sonic bath for 2 hours. GO suspension magnetically stirred and 140mg of (CH<sub>3</sub>COO)<sub>2</sub>Co·6H<sub>2</sub>O added to the suspension when temperature reaches 50 °C. Mixture then magnetically stirred at 50 °C for 1 hour. Mixture then autoclaved at 180 °C for 12 hours. When mixture has cooled down to room temperature, it was vacuum filtered and washed with D.I. water and ethanol for at least three times each. Obtained sample vacuum dried at room temperature overnight. Finally, the dried sample was calcined at 250 °C for 2hrs at 5 °C/min.

### 2.2.2 Preparation of rGO/Co<sub>3</sub>O<sub>4</sub> electrodes

The obtained rGO/Co<sub>3</sub>O<sub>4</sub> sample was mixed with 15 wt% SuperP as conductive material and 5 wt% PTFE as binder material. The obtained flake-like composite was deposited onto 1cm x 10cm large nickel foam by pressure. Full cell was made throughout the whole research. Therefore two electrodes with the composite were made. 6M KOH was used as the electrolyte.

### 2.3 Characterization of rGO/Co<sub>3</sub>O<sub>4</sub> pseudocapacitor

### 2.3.1 Electrochemical measurement for electrochemical performance of pseudocapacitor

Three electrode system was constructed using Hg/HgO as the reference electrode, Pt as the counter electrode, and the nickel foam and active material as the working electrode. 5M KOH was used as the electrolyte. A battery cycler (WBCS3000, WonATech) was used for cyclic voltammetry and galvanostatic charge/discharge at a fixed potential window of 0.543V at a scan rate of 1, 5 mV/s and 1, 2, 5 Ag<sup>-1</sup> for the asmade pseudocapacitors.

### 2.3.2 Physicochemical analysis of pseudocapacitor

The content of carbon and oxygenated carbon within the GO were investigated by the X-ray photoelectron spectroscopy (XPS; Sigma Probe, Thermo Scientific). The surface characterization of rGO was carried out by powder X-ray diffraction (PXRD; D8 Advance, Bruker) using Ni-filtered Cu K $\alpha$  radiation ( $\lambda$  = 0.154184 nm). The morphologies of rGO/Co<sub>3</sub>O<sub>4</sub> composite was characterized by scanning electron microscopy (SEM; JSM-6700F, JEOL), and analytical transmission electron microscopy (Analytical TEM; Tecnai F20, FEI).

### 3. Results and Discussion

### 3.1 Electrochemical and physicochemical analysis of rGO/Co<sub>3</sub>O<sub>4</sub>(C) and rGO/Co<sub>3</sub>O<sub>4</sub> (P)

### 3.1.1 Electrochemical performance and structural analysis of rGO and $\text{Co}_3\text{O}_4$

The cyclic voltammetry (CV) analysis was used for the measurement of solely rGO supercapacitor. As seen in Figure 10:

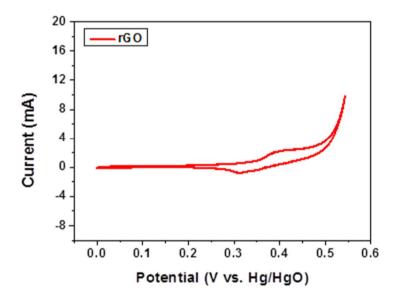


Figure 10: Cyclic voltammetry of rGO

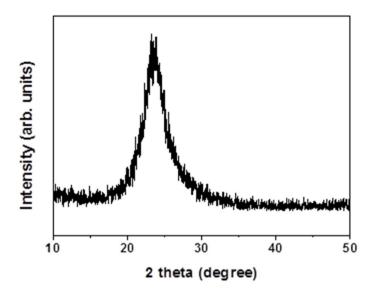


Figure 11: XRD of rGO

We can see that the rGO supercapacitor shows an EDLC behavior as discussed in the introduction section. It has an almost symmetrical rectangular shape with no particular pseudocapacitive peaks suggesting that only electrostatic reactions has happened between the rGO electrodes and the 6M KOH electrolyte ions. And it can be seen from the XRD in Figure 11, confirming that the sample made show its characteristic rGO peak around  $\theta = 25^{\circ}$ .

We also fabricated a pseudocapacitor with  $\text{Co}_3\text{O}_4$  nanoparticles only and the CV curve as seen in Figure 12:

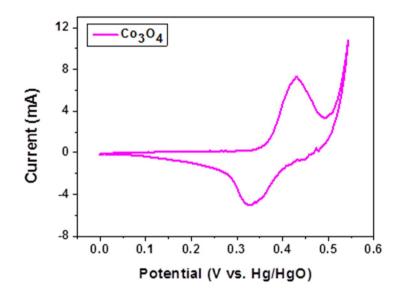


Figure 12: Cyclic voltammetry of Co<sub>3</sub>O<sub>4</sub>

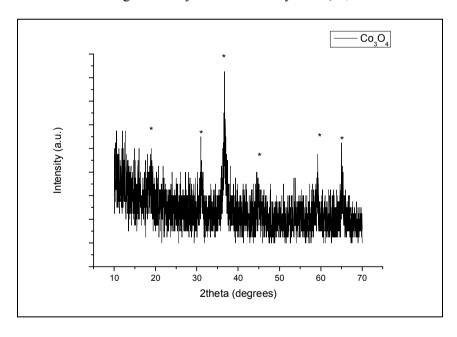


Figure 13: XRD of Co<sub>3</sub>O<sub>4</sub>

Compared to the rGO supercapacitor, which showed an EDLC behavior, the  $Co_3O_4$  pseudocapacitor show a sharp pseudocapacitive peak at a potential around 0.43V, suggesting that there is definitely an electrochemical reaction happenening between the metal oxides and the electrolyte ions. It can also be seen from Figure 13 that the following sample is well fabricated with indicative  $Co_3O_4$  peaks at  $\theta = 18.9$  °, 30.9 °, 36.7 °, 45.3 °, 59.2 °, 65.0 °.

### 3.1.2 Electrochemical performance of $rGO/Co_3O_4(C)$ and $rGO/Co_3O_4(P)$

Figure 14 shows the CV curve of rGO/Co<sub>3</sub>O<sub>4</sub>(C) and rGO/Co<sub>3</sub>O<sub>4</sub>(P) composite measured and the specific capacitance values were calculated using equation (1).

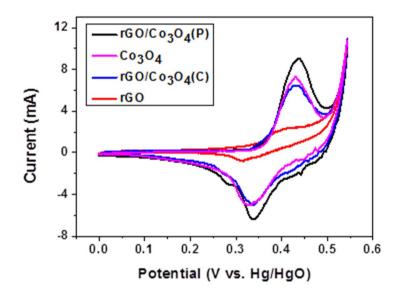


Figure 14: Cyclic voltammetry of rGO/Co $_3O_4(P),$  rGO/Co $_3O_4(C),$  Co $_3O_4,$  and rGO at 5 mV/s

Table 2: Calculated pecific capacitance values of rGO, Co $_3$ O $_4$ , rGO/Co $_3$ O $_4$ (C), rGO/Co $_3$ O $_4$ (P) at 1 A/g

Samples	Specific capacitance (F/g)
rGO	154.8
Co <sub>3</sub> O <sub>4</sub>	176.6
rGO/Co <sub>3</sub> O <sub>4</sub> (C)	178.5
rGO/Co <sub>3</sub> O <sub>4</sub> (P)	207.2

As seen in Figure 14, we can see that more pseudocapacitive peak is shown in the  $rGO/Co_3O_4(P)$  while the peaks are merely shown in  $rGO/Co_3O_4(C)$ . Table 2 shows the calculated specific capacitance of rGO supercapacitor,  $Co_3O_4$ ,  $rGO/Co_3O_4(C)$ , and  $rGO/Co_3O_4(P)$  pseudocapacitors at 1 Ag<sup>-1</sup>. From this table, we can see that the  $rGO/Co_3O_4(P)$  pseudocapacitor show highest specific capacitance compared to the  $rGO/Co_3O_4(C)$ , suggesting that rGO(P) is a more suitable substrate for growing well dispersed  $Co_3O_4$  nanoparticles.

Before going into details of analyzing why the samples show different electrochemical performances, an XRD analysis of the composites confirm that the Co<sub>3</sub>O<sub>4</sub> nanoparticles were well fabricated in the rGO composites as shown in Figure 15.

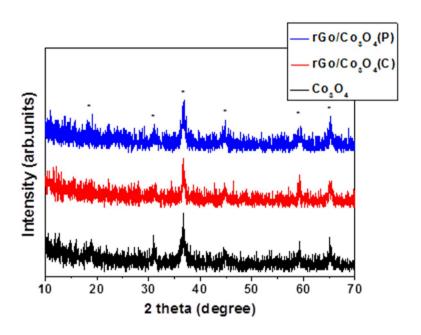
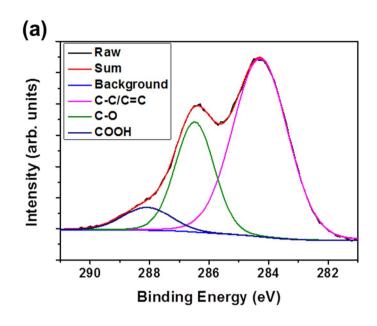


Figure 15: XRD of Co<sub>3</sub>O<sub>4</sub>, rGO/Co<sub>3</sub>O<sub>4</sub>(P), rGO/Co<sub>3</sub>O<sub>4</sub>(C)

### 3.1.3 Physicochemical analysis of GO(C) and GO(P)

The XPS data in Figure 16a and b show the deconvoluted C1s peak of GO(C) and GO(P). From this figure, we can see that the C-C and C-OH peaks are very similar to each other suggesting that both GO(C) and GO(P) have similar amount of functional groups.



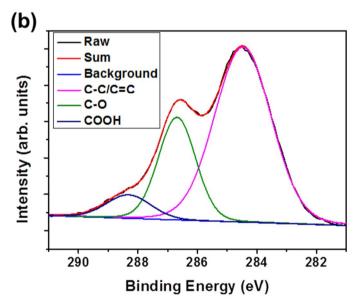


Figure 16: Deconvoluted C1s peak of XPS data of a) GO(P) and b) GO(C)

The percentages of oxygenated carbon was calculated from the XPS data of GO(P) and GO(C) and is summarized in Table 3:

Table 3: Amount of oxygenated carbon calculated from the XPS data of GO(P) and GO(C)

Samples	C=C (%)	C-O (%)	O-C=O (%)
GO(P)	64.4	28.3	7.3
GO(C)	67.1	25.9	7.0

From Table 3, we can see that GO(C) and GO(P) have very similar amount of functional groups, therefore we want to emphasize that the amount of functional groups is not a controlling parameter of this part of the research. The growth of metal oxides was not affected by the number of functional groups.

We also took SEM and TEM images in order to analyze the morphologies of how the  $Co_3O_4$  nanoparticles were grown on the surface of rGO(P) and rGO(C). As seen in Figure 17a and b, we can clearly see the difference between the two composites. For  $rGO/Co_3O_4(P)$ , the  $Co_3O_4$  nanoparticles are well dispersed between the sheets and the MO particles are well packed amongst each other while for  $rGO/Co_3O_4(C)$ , the growth of MO particles itself cannot be clearly seen. Rather, the particles are only grown on some parts or not grown at all. From this we can conclude that rGO(P) is a more suitable substrate for growing metal oxide nanoparticles.

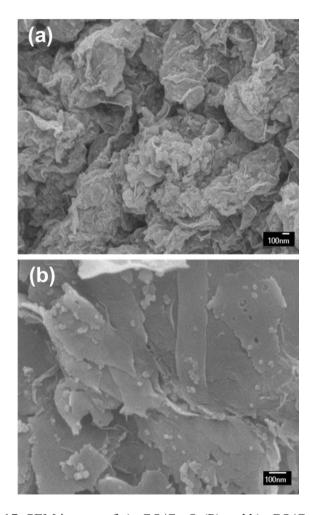


Figure 17: SEM images of a)  $rGO/Co_3O_4(P)$  and b)  $rGO/Co_3O_4(C)$ 

- 3.2 Electrochemical and physicochemical analysis of  $rGO/Co_3O_4(P-0), \qquad rGO/Co_3O_4(P-4), \qquad rGO/Co_3O_4(P-8), \\ rGO/Co_3O_4(P-16)$ 
  - 3.2.1 Physicochemical analysis of GO(P-0), GO(P-4), GO(P-8), GO(P-16) and rGO/Co<sub>3</sub>O<sub>4</sub>(P-0), rGO/Co<sub>3</sub>O<sub>4</sub>(P-4), rGO/Co<sub>3</sub>O<sub>4</sub>(P-8), rGO/Co<sub>3</sub>O<sub>4</sub>(P-16)

The XPS data in Figure 18 show the deconvoluted C1s peak of GO treated at 4 different oxidation times – 0h, 4h, 8h, 16h. From this figure, we can see that the C-C and C-OH peaks differ between GO treated at 0h and 16h. It can be seen that the area of the C-O peaks increase as the oxidation time increases indicating an increase in oxygen functional groups. This was thus shown in a bar graph shown in Figure 20. From this Figure, we can see that as the C-O bond increases, the C-C bond decreases with, which is again shown in Table 4.

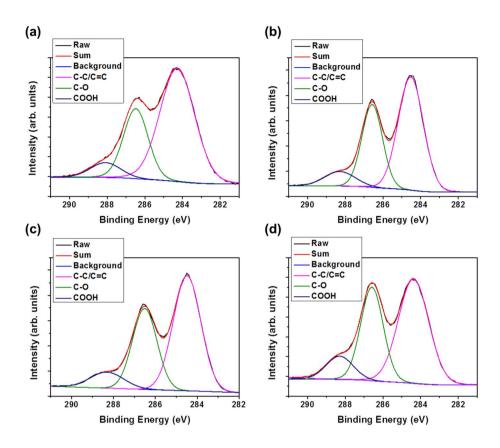


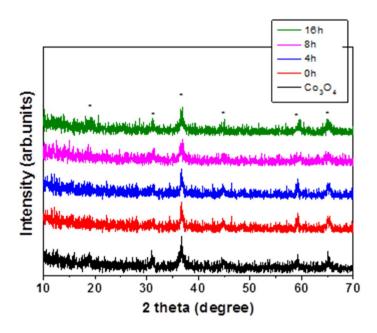
Figure 18: Deconvoluted C1s peak of XPS data of (a) GO(P-0) and (b) GO(P-4) (c) GO(P-8) (d) GO(P-16).

Table 4: Percentages of oxygenated carbon calculated from the XPS data of GO(P-0), GO(P-4), GO(P-8), GO(P-16)

Samples	C=C (%)	C-O (%)	O-C=O (%)
GO(P-0)	64.4	28.3	7.3
GO(P-4)	56.9	34.2	8.9
GO(P-8)	55.8	34.8	9.4
GO(P-16)	53.7	35.7	10.6

From Table 4, it can be seen that the percentage of oxygenated carbon increases with oxidation time of GO. This is because the contact time between  $MnO_4^-$  and GO increases with the oxidation time. The more GO is exposed to  $MnO_4^-$ , the more functional groups are attached to the surface of GO.

Now that we have confirmed that the functional groups of GO increase with the oxidation time, we utilized the four different types of GO into fabricating  $rGO/Co_3O_4-0h$ , 4h, 8h, 16h. We first were able to confirm from the XRD that all four composites were well fabricated with  $Co_3O_4$  well incorporated into the composite as shown in Figure 19 with the indicative  $Co_3O_4$  peaks.



 $\label{eq:Figure 19: XRD of Co_3O_4, rGO/Co_3O_4(P-0), rGO/Co_3O_4(P-4), rGO/Co_3O_4(P-8), \\ rGO/Co_3O_4(P-16) \\$ 

After confirming that the composites were all well fabricated with indicative  $Co_3O_4$  nanoparticles, we took SEM and TEM images of the four different types of composites in order to analyze the morphology of the composites. As seen in Figure 20a, b, c, d, we can see that for  $rGO/Co_3O_4(P-0)$  and  $rGO/Co_3O_4(P-4)$ , the  $Co_3O_4$  nanoparticles are only grown on some parts of the GO surface. Some parts don't have any  $Co_3O_4$  nanoparticles grown at all. For  $rGO/Co_3O_4(P-8)$  and  $rGO/Co_3O_4(P-16)$ , we can see that the  $Co_3O_4$  particles are actually very well dispersed onto the surface of GO.

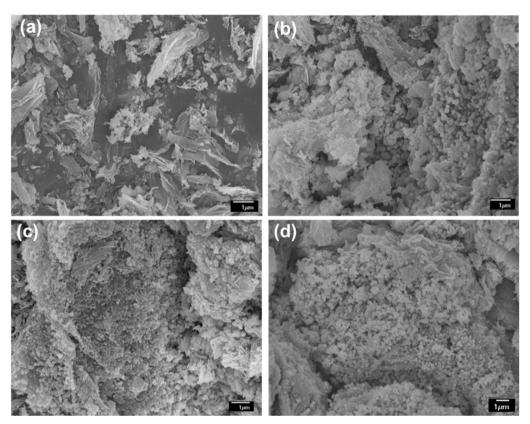


Figure 20: SEM images of (a)  $rGO/Co_3O_4(P-0)$  (b)  $rGO/Co_3O_4(P-4)$  (c)  $rGO/Co_3O_4(P-8)$  (d)  $rGO/Co_3O_4(P-16)$ .

In order to look into the morphology into more detail in regarding the sizes of the  $Co_3O_4$  nanoparticles, we took TEM images of the four composites. As shown in Figure 21a, b, c, d, we can see that for  $rGO/Co_3O_4(P-0)$  and  $rGO/Co_3O_4(P-4)$ , the  $Co_3O_4$  nanoparticles are grown into each other into very biz sized nanoparticles while for  $rGO/Co_3O_4(P-8)$  and  $rGO/Co_3O_4(P-16)$ , the  $Co_3O_4$  nanoparticles are well dispersed onto the sheets of graphene oxide showing that the MO particles are well pinned between the functional groups and therefore not growing into each other.

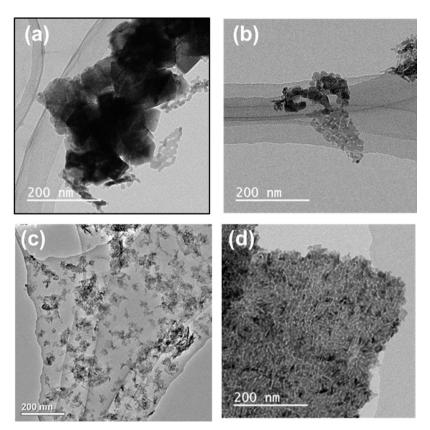


Figure 21: TEM images of (a)  $rGO/Co_3O_4(P-0)$  (b)  $rGO/Co_3O_4(P-4)$  (c)  $rGO/Co_3O_4(P-8)$  (d)  $rGO/Co_3O_4(P-16)$ .

The particle sizes were approximated from the TEM images and were put into Table 5:

Table 5: Particle sizes and surface coverage of Co<sub>3</sub>O<sub>4</sub> grown on rGO/Co<sub>3</sub>O<sub>4</sub>(P-0), rGO/Co<sub>3</sub>O<sub>4</sub>(P-4), rGO/Co<sub>3</sub>O<sub>4</sub>(P-8), rGO/Co<sub>3</sub>O<sub>4</sub>(P-16)

Samples	rGO/C <sub>03</sub> O <sub>4</sub> (P-0)	rGO/Co <sub>3</sub> O <sub>4</sub> (P-	rGO/Co <sub>3</sub> O <sub>4</sub> (P-	rGO/Co <sub>3</sub> O <sub>4</sub> (P-
Size (nm)	54.3±18.4	26.3±6.3	9.4±1.9	5.9±1.5
Surface coverage (%)	17.6	30.3	66.2	73.4

From Table 5, we can see that the  $Co_3O_4$  particle size decreases while surface coverage increases with the increasing oxidation time and thus with the increasing functional groups because of the reasons explained above. The smaller sizes of  $Co_3O_4$  particles help them to be more dispersed well on the rGO's surface, thus, providing more available redox reaction sites for the pseudocapacitor..

EDS measurements were also taken along with the TEM images in order to confirm that the  $Co_3O_4$  nanoparticles were well grown on the surfaces of rGO, which is shown in Figure 22. rGO/ $Co_3O_4$ (P-16) sample was taken into account owing to its abundancy of  $Co_3O_4$  nanoparticles dispersed onto the surface of rGO. As seen in Figure 22, according to the elemental analysis, cobalt particles can be much more distinctly seen than the carbon detected, indicating that the  $Co_3O_4$  nanoparticles are well grown and dispersed throughout the surface of rGO.

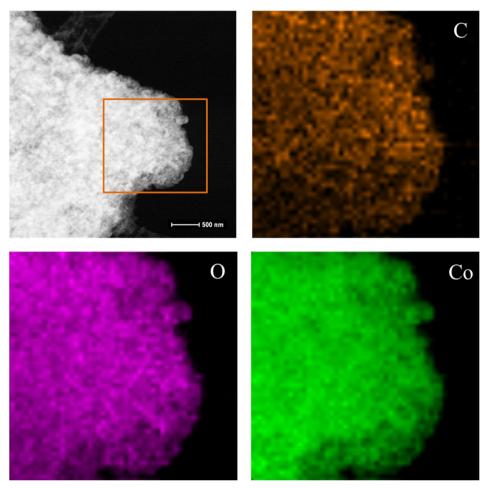


Figure 22: EDS measurements of rGO/Co<sub>3</sub>O<sub>4</sub>(P-16)

# 3.2.2 Electrochemical analysis of $rGO/Co_3O_4(P-0)$ , $rGO/Co_3O_4(P-4), \ rGO/Co_3O_4(P-8), \ rGO/Co_3O_4(P-16)$

CV measurement was done on the four different composites as shown in

Figure 23. All 4 curves show strong redox peaks indicating faradaic reaction between the  $Co_3O_4$  nanoparticles and the KOH electrolyte ions. Such redox peaks result from the conversion of cobalt oxidation states shown in the following electrochemical reactions:

$$Co_3O_4 + OH^- + H_2O \leftrightarrow 3CoOOH + e^-$$

$$CoOOH + OH^- \leftrightarrow CoO_2 + H_2O + e^-$$

where two redox couples, Co<sub>3</sub>O<sub>4</sub>/CoOOH and CoOOH/CoO<sub>2</sub> are involved. As the area under the curve increase with the oxidation time, the corresponding peaks increase also. This is because, as discussed just before, rGO/Co<sub>3</sub>O<sub>4</sub>(P-16) has much more Co<sub>3</sub>O<sub>4</sub> nanoparticles to faradaically react with the electrolyte ions increasing the accumulation of charges at the certain voltage. This, thus, confirms that our expectation was correct about the availability of redox reaction sites and its relation to the behavior of a pseudocapacitor. Equation 1 was again used to calculate the specific capacitances of the four composites, which are shown in Table 6.

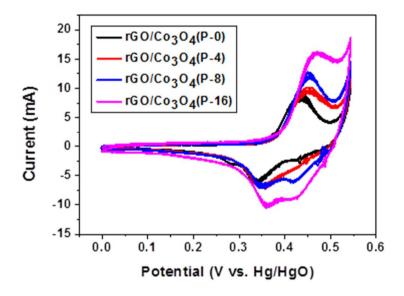


Figure 23: Cyclic voltammograms of  $rGO/Co_3O_4(P-0)$ ,  $rGO/Co_3O_4(P-4)$ ,  $rGO/Co_3O_4(P-8)$ ,  $rGO/Co_3O_4(P-16)$  at 5 mV/s

Table 6: Calculated specific capacitance values of  $rGO/Co_3O_4(P-0)$ ,  $rGO/Co_3O_4(P-4)$ ,  $rGO/Co_3O_4(P-8)$ ,  $rGO/Co_3O_4(P-16)$  at  $1~Ag^{-1}$ 

Samples	Specific capacitance (F/g)
rGO/Co <sub>3</sub> O <sub>4</sub> (P-0)	207.2
rGO/Co <sub>3</sub> O <sub>4</sub> (P-4)	244.9
rGO/Co <sub>3</sub> O <sub>4</sub> (P-8)	320.5
rGO/Co <sub>3</sub> O <sub>4</sub> (P-16)	411.5

As shown in Table 6, we can see that the specific capacitance increases with the oxidation time and thus with the functional groups attached on GO due to the reasons that were stated above.

#### 3.3 Correlation graphs

From the final results, we were able to come up with two correlation graphs. The first, shown in Figure 24a, relate the specific capacitance values between rGO,  $Co_3O_4$ ,  $rGO/Co_3O_4(C)$ , and  $rGO/Co_3O_4(P)$ . From this graph, we can conclude that the specific capacitance is low for the rGO and  $Co_3O_4$  pseudocapacitors alone while it increases a little for the  $rGO/Co_3O_4(C)$ . However, the  $rGO/Co_3O_4(P)$  has the highest specific capacitance because it is a more suitable substrate for growing MO particles.

From Figure 25b, we were able to conclude that the specific capacitance value increases with the oxidation time and thus with the functional groups attached on the surface of GO because of the availability of redox reaction sites in the one with many functional groups.

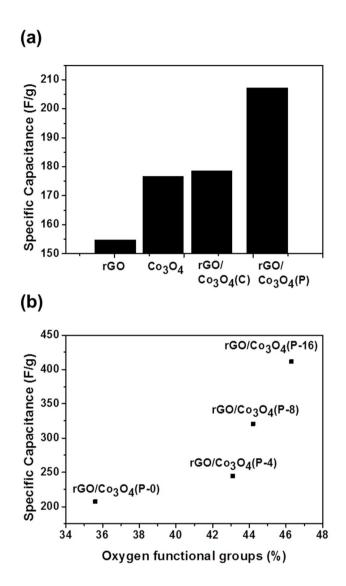


Figure 24: Correlation graphs of (a) specific capacitance vs. samples  $rGO/Co_3O_4(P-0)$ ,  $rGO/Co_3O_4(P-4)$ ,  $rGO/Co_3O_4(P-8)$ ,  $rGO/Co_3O_4(P-16)$  at 1 A/g. (b) specific capacitance vs. oxygen functional groups for  $rGO/Co_3O_4(P-0)$ ,  $rGO/Co_3O_4(P-4)$ ,  $rGO/Co_3O_4(P-8)$ ,  $rGO/Co_3O_4(P-16)$  at 1 A/g.

#### 4. Conclusion

From this research, we were able to re-visit the oxidation of GO by controlling the oxidation time of GO and investigate its effect in the growth of metal oxides and prove that there is a difference in electrochemical performance for differently oxidized GO with different amount of functional groups attached.

We can first conclude, that rGO and Co<sub>3</sub>O<sub>4</sub>pseudocapacitor alone shows poor electrochemical performance. And though they had similar amount of functional groups, rGO/Co<sub>3</sub>O<sub>4</sub>(P) showed better electrochemical performance. Co<sub>3</sub>O<sub>4</sub> particles were well dispersed onto the surface of planar rGO, confirming that rGO(P) is more suitable for growing metal oxide nanoparticles.

Secondly, we were able to conclude that rGO/Co<sub>3</sub>O<sub>4</sub> composite fabricated from GO treated for 16h showed the highest electrochemical performance. The more oxygen functional groups, the more nucleation sites for metal oxides to grow in smaller sizes and disperse well, thus, leading to higher specific capacitance value.

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## 국문 초록

이 논문은 환원된 그래핀 옥사이드의 표면특성이 유사커패시터의 성능에 미치는 영향에 대해 연구한 것이다. 환원된 그래핀 옥사이드의 여러 가지 뛰어난 성능으로 인해 이를 적용하려는 다양한 연구가 진행되고 있다. 그 중에서도 금속산화물을 환원된 그래핀 옥사이드의 표면에 성장시켜 유사커패시터의 전극 물질로 사용하는 연구가 진행되고 있다. 금속산화물을 다기공성의 환원된 그래핀 옥사이드에 성장시킬 경우, pseudocapacitive한 특성과 specific capacitance가 향상되는데, 이는 금속산화물의 잘 알려진 redox mechanism과 환원된 그래핀 옥사이드의 높은 전기전도도 덕분이다. 그러나 기존의 연구들은 금속산화물의 성장이 환원된 그래핀 옥사이드의 표면 특성의 개질에 따라 어떠한 차이를 보이는지에 대한 답을 제시하지 않고 성능을 높이는 데에 집중하였다. 따라서 본 연구에서는 그래핀 옥사이드의 표면에 존재 하는 작용기의 양을 조절하여 금속산화물의 성장에 어떠한 영향을 끼치는지 확인하였다. 그래핀 옥사이드에 존재하는 작용기의 양은 산화시간을 조절하여 변화시켰고, 이를 XPS를 통해 확인하였다. 이에 따라 성장한 금속산화물의 크기와 분산도는 SEM과 TEM 측정을 통해확인하였으며, 제작한 환원된 그래핀 옥사이드/금속산화물 복합체의 specific capacitance는 cyclic voltammetry를 통해 측정하였다. 그결과 그래핀 옥사이드에 존재하는 작용기의 양이 증가할수록 금속산화물의 크기는 감소하며 분산도는 증가하였고 이에 따라 specific capacitance도 증가하였다.

본 연구는 그래핀 옥사이드의 표면 특성에 따른 금속산화물의 성장 및 분산도를 다양한 분석방법을 통해 다각도로 분석하고, 유사커패시터로서의 전기화학적 성능을 확인하였고, 앞으로 그래핀을 이용한 유사커패시터의 제작에 가이드라인이 될 것이라고 생각한다.

주요어 : 환원된 그래핀 옥사이드, 산화작용기, 금속산화물, 전기화학, 유사캐패시터.

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